REGULATOR DIODES

Glass passivated diodes in hermetically sealed axial-leaded glass envelopes. They are intended for use as voltage regulator and transient suppressor diode in medium power regulation and transient suppression circuits.

The series consists of BZW03-C7V5 to BZW03-C510 in the normalized E24 range.

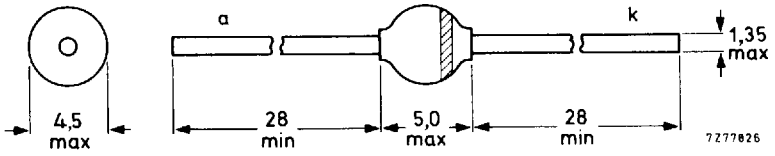
QUICK REFERENCE DATA

			voltage regulator	transient suppressor	
Working voltage range	V_Z	nom.	7,5 to 270		V
Stand-off voltage	V_R			6,2 to 430	V
Total power dissipation	P_{tot}	max.	6		W
Non-repetitive peak reverse power dissipation $T_j = 25\ ^oC$; $t_p = 100\ \mu s$	P_{RSM}			1000	W

MECHANICAL DATA

Dimensions in mm

Fig. 1 SOD-64.



The marking band indicates the cathode.

Products approved to CECC 50 005-019.

RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134)

Total power dissipation			
T_{tp} = 25 °C; lead length 10 mm	P_{tot}	max.	6 W
T_{amb} = 45 °C; p.c.b. mounting (Fig. 2)	P_{tot}	max.	1,75 W
Repetitive peak reverse power dissipation	P_{ZRM}	max.	20 W
Non-repetitive peak reverse power dissipation			
t_p = 100 μs square pulse; T_j = 25 °C (prior to surge)	P_{RSM}	max.	1000 W
waveform 10/1000 exponential pulse (see Fig. 3), T_j = 25 °C (prior to surge)	P_{RSM}	max.	500 W
Storage temperature	T_{stg}		−65 to +175 °C
Junction temperature	T_j	max.	175 °C

THERMAL RESISTANCE

Influence of mounting method

1. Thermal resistance from junction to tie-point at a lead length of 10 mm	$R_{th\ j\text{-}tp}$	=	25 K/W
2. Thermal resistance from junction to ambient when mounted on a 1,5 mm thick epoxy-glass printed-circuit board; Cu-thickness ≥ 40 μm; Fig. 2 (see "Thermal model")	$R_{th\ j\text{-}a}$	=	75 K/W

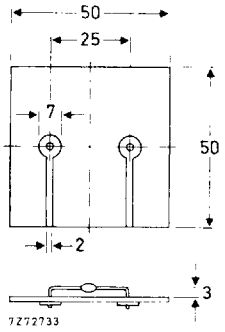


Fig. 2 Mounted on a printed-circuit board.

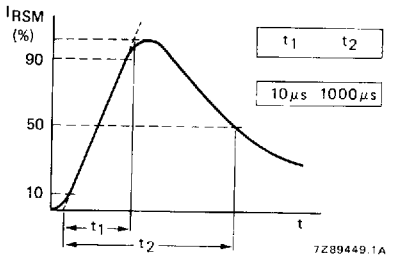


Fig. 3 Current pulse according to IEC 60-2, Section 6.

CHARACTERISTICS

Forward voltage			
I_F = 1 A; T_j = 25 °C	V_F	<	1,2 V

CHARACTERISTICS when used as voltage regulator diodes; T_j = 25 °C

	working voltage V_Z V			differential resistance r_{diff} Ω		temperature coefficient S_Z %/K		test current I_Z mA	reverse current I_R μA at reverse voltage V_R V	
BZW03-	min.	nom.	max.	typ.	max.	min.	max.		max.	
C7V5	7,0	7,5	7,9	0,7	1,5	0	0,07	175	1500	5,6
C8V2	7,7	8,2	8,7	0,8	1,5	0,03	0,08	150	1200	6,2
C9V1	8,5	9,1	9,6	0,9	2,0	0,03	0,08	150	40	6,8
C10	9,4	10,0	10,6	1,0	2,0	0,05	0,09	125	20	7,5
C11	10,4	11,0	11,6	1,1	2,5	0,05	0,10	125	15	8,2
C12	11,4	12,0	12,7	1,1	2,5	0,05	0,10	100	10	9,1
C13	12,4	13,0	14,1	1,2	2,5	0,05	0,10	100	4	10
C15	13,8	15,0	15,6	1,2	2,5	0,05	0,10	75	2	11
C16	15,3	16,0	17,1	1,3	2,5	0,06	0,11	75	2	12
C18	16,8	18,0	19,1	1,3	2,5	0,06	0,11	65	2	13
C20	18,8	20,0	21,2	1,5	3	0,06	0,11	65	2	15
C22	20,8	22,0	23,3	1,6	3,5	0,06	0,11	50	2	16
C24	22,8	24,0	25,6	1,8	3,5	0,06	0,11	50	2	18
C27	25,1	27,0	28,9	2,5	5	0,06	0,11	50	2	20
C30	28	30	32	4	8	0,06	0,11	40	2	22
C33	31	33	35	5	10	0,06	0,11	40	2	24
C36	34	36	38	6	11	0,06	0,11	30	2	27
C39	37	39	41	7	14	0,06	0,11	30	2	30
C43	40	43	46	10	20	0,07	0,12	30	2	33
C47	44	47	50	12	25	0,07	0,12	25	2	36
C51	48	51	54	14	27	0,07	0,12	25	2	39
C56	52	56	60	18	35	0,07	0,12	20	2	43
C62	58	62	66	20	42	0,08	0,13	20	2	47
C68	64	68	72	22	44	0,08	0,13	20	2	51
C75	70	75	79	25	45	0,08	0,13	20	2	56
C82	77	82	87	30	65	0,08	0,13	15	2	62
C91	85	91	96	40	75	0,09	0,13	15	2	68
C100	94	100	106	45	90	0,09	0,13	12	2	75
C110	104	110	116	65	125	0,09	0,13	12	2	82
C120	114	120	127	90	170	0,09	0,13	10	2	91
C130	124	130	141	100	190	0,09	0,13	10	2	100
C150	138	150	156	150	330	0,09	0,13	8	2	110
C160	153	160	171	180	350	0,09	0,13	8	2	120
C180	168	180	191	210	430	0,09	0,13	5	2	130
C200	188	200	212	250	500	0,09	0,13	5	2	150
C220	208	220	233	350	700	0,09	0,13	5	2	160
C240	228	240	256	450	900	0,09	0,13	5	2	180
C270	251	270	289	600	1200	0,09	0,13	5	2	200

CHARACTERISTICS when used as transient suppressor diodes; T_j = 25 °C

clamping voltage at non-repetitive peak reverse current 10/1000 pulse		reverse current at recommended stand-off voltage		
$V_{(CL)R}$ V	I_{RSM} A	I_R μA	V_R V	
max.	max.	max.		BZW03-
11,3	44,2	3000	6,2	C7V5
12,3	40,6	2400	6,8	C8V2
13,3	37,6	100	7,5	C9V1
14,8	34,0	40	8,2	C10
15,7	31,8	30	9,1	C11
17,0	29,4	20	10	C12
18,9	26,4	10	11	C13
20,9	23,9	10	12	C15
22,9	21,8	10	13	C16
25,6	19,5	10	15	C18
28,4	17,6	10	16	C20
31	16,1	10	18	C22
33,8	14,8	10	20	C24
38,1	13,1	10	22	C27
42,2	11,8	10	24	C30
46,2	10,8	10	27	C33
50,1	10,0	10	30	C36
54,1	9,2	10	33	C39
60,7	8,2	10	36	C43
65,5	7,6	10	39	C47
70,8	7,0	10	43	C51
78,6	6,3	10	47	C56
86,5	5,8	10	51	C62
94,4	5,3	10	56	C68
103,5	4,8	10	62	C75
114,0	4,3	10	68	C82
126	3,9	10	75	C91
139	3,6	10	82	C100
152	3,3	10	91	C110
167	3,0	10	100	C120
185	2,7	10	110	C130
204	2,4	10	120	C150
224	2,2	10	130	C160
249	2,0	10	150	C180
276	1,8	10	160	C200
305	1,6	10	180	C220
336	1,5	10	200	C240
380	1,3	10	220	C270
419	1,2	10	240	C300
459	1,1	10	270	C330
498	1,0	10	300	C360
537	0,93	10	330	C390
603	0,83	10	360	C430
655	0,76	10	390	C470
707	0,71	10	430	C510

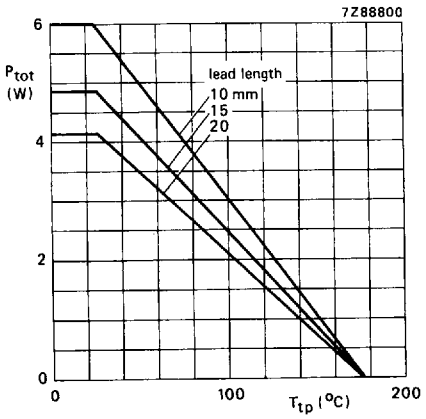


Fig. 4 Maximum total power dissipation as a function of tie-point temperature.

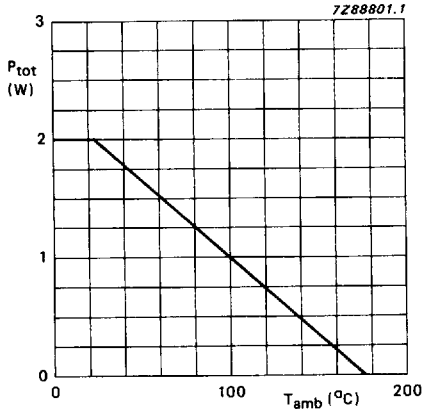


Fig. 5 Maximum total power dissipation as a function of ambient temperature, mounted as shown in Fig. 2.

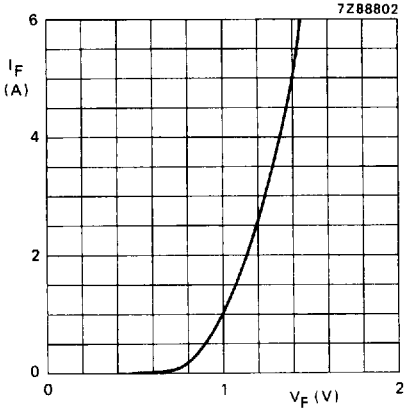


Fig. 6 Typical forward voltage drop at T_j = 25 °C.

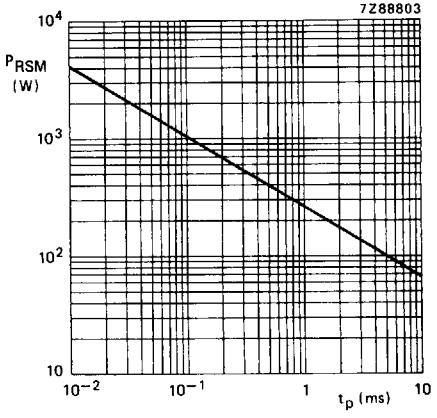


Fig. 7 Maximum non-repetitive peak reverse power dissipation; square current pulse; T_j = 25 °C prior to surge.

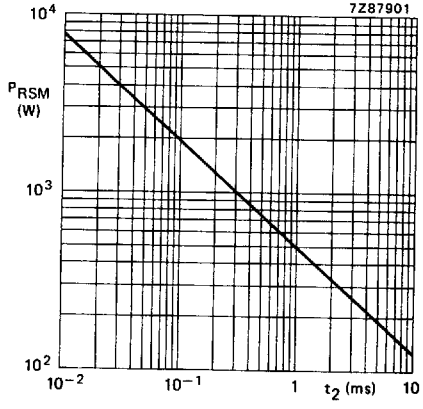


Fig. 8 Maximum non-repetitive peak reverse power dissipation; exponential pulse; T_j = 25 °C prior to surge.